

Manipulating Coherence of Near-Field Thermal Radiation in Time-Modulated Systems

Renwen Yu¹ and Shanhui Fan^{1*}*Department of Electrical Engineering, Ginzton Laboratory, Stanford University, Stanford, California 94305, USA*

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We show that the spatial coherence of thermal radiation can be manipulated in time-modulated photonic systems supporting surface polaritons. We develop a fluctuational electrodynamics formalism for such systems to calculate the cross-spectral density tensor of the emitted thermal electromagnetic fields in the near-field regime. Our calculations indicate that, due to time-modulation, spatial coherence can be transferred between different frequencies, and correlations between different frequency components become possible. All these effects are unique to time-modulated systems. We also show that the decay rate of optical emitters can be controlled in the proximity of such time-modulated structure. Our findings open a promising avenue toward coherence control in thermal radiation, dynamical thermal imaging, manipulating energy transfer among thermal or optical emitters, efficient near-field radiative cooling, and engineering spontaneous emission rates of molecules.

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Controlling thermal emission is crucial for many applications, such as passive radiative cooling [1], solar thermophotovoltaic energy conversion [2], and incandescent lighting [3,4]. Recent developments in near-field nanophotonics have provided new possibilities for enhanced radiative cooling [5], thermophotovoltaic energy conversion [6–8], and imaging [9]. Near-field radiative heat transfer is also of fundamental importance to explore fluctuation physics at nanoscale [10–29] in various aspects, including vacuum friction [30,31], persistent heat current at equilibrium [32], and ultrafast radiative heat transfer [33].

Most studies on controlling thermal emission are carried out with passive systems. But recent works have pointed to new effects in active systems where the refractive indices are modulated as a function of time [34–38]. For example, in Ref. [36], temporal modulation of the material permittivity is used to initiate an energy transfer between two optical resonances and to achieve active cooling in the far-field regime. Since, in the broader photonics context, temporal modulation has created promising new opportunities for photon management, such as frequency conversion [39,40], optical isolation [41,42], and optical temporal aiming [43], it should be of interest to further explore the consequence of temporal modulation on thermal radiation.

A key characteristics of thermal radiation is its coherence property. Conventional thermal emitters can be well approximated by a blackbody, and its thermally emitted electromagnetic fields are incoherent in the far-field regime. In contrast, in the near-field regime, an enhanced coherence of thermal radiation from planar structures made of either noble metals or polar materials has been theoretically proposed [10] and experimentally demonstrated [44]. This near-field coherence enhancement is due to the surface plasmon or phonon polaritons supported by these

structures, and occurred only at the frequencies near the surface polariton resonances. Further nanophotonic structuring can transfer the enhanced coherence into the far field, leading to a coherent emission of light from thermal sources [45]. However, all existing studies on coherence properties of thermal radiation consider only passive systems.

In this work, we study the spatial coherence of thermal radiation in time-modulated active systems. As an example, we consider a planar structure consisting of a plasmon or phonon polaritonic substrate and a dielectric thin film. We study the coherence properties of its thermally emitted electromagnetic fields in the near-field regime when the dielectric thin film is undergoing a permittivity modulation. Our study reveals several unique characteristics in the coherence properties. We show that the strong coherence can be observed at frequencies away from the surface polariton resonances, due to the transfer of coherence as induced by temporal modulation. Also, the temporally modulated system exhibits cross-frequency correlation, i.e., coherence between thermal radiations at different frequencies. None of these properties exist in passive structures. To study this system, we have developed a fluctuational electrodynamics formalism for time-modulated systems. Our formalism further reveals that the local density of states in the near field can be strongly affected due to temporal modulation. Thus, temporal modulation enables a novel pathway to control the decay rate of optical emitters.

As the model system in this Letter, in Fig. 1(a), we consider a time-modulated lossless layer (green region) on top of a semi-infinite substrate composed of a Drude metal (blue region). The permittivity of the Drude metal is assumed to be $\epsilon(\omega) = 1 - [\omega_p^2 / \omega(\omega + i\gamma)]$, with

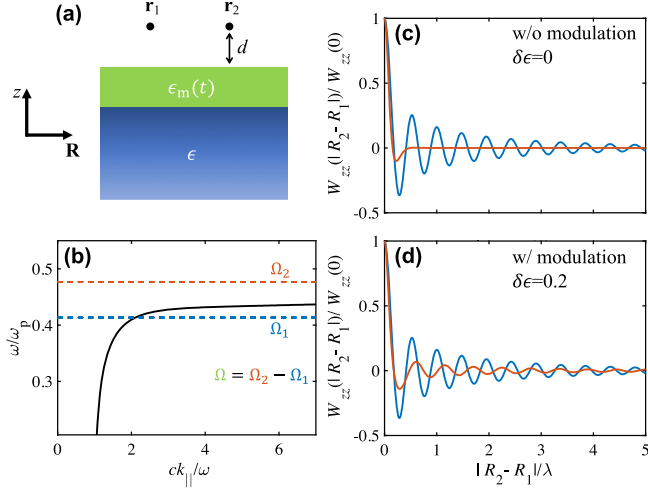


FIG. 1. (a) Schematic of a photonic system composed of a time-modulated lossless layer (green region) on top of a substrate made of a Drude metal (blue region) with a plasma frequency ω_p . We consider the spatial correlation of the thermally emitted electric fields at two points \mathbf{r}_1 and \mathbf{r}_2 in vacuum. Both points are separated from the material surface by a vertical distance of $d = 1 \mu\text{m}$. (b) Dispersion relation (black solid curve) of the surface plasmon mode sustained in the system shown in panel (a). (c),(d) Normalized element W_{zz} of the cross-spectral density tensor as a function of the normalized lateral separation distance $|R_1 - R_2|/\lambda$ between those two points shown in panel (a), without (c) or with [(d), modulation strength $\delta\epsilon = 0.2$] time modulation. Blue and red curves represent W_{zz} evaluated at two frequencies Ω_1 and Ω_2 as labeled in panel (b). $\lambda = 2\pi c/\omega$ is the light wavelength for the respective frequency in vacuum, and thus is different for the blue and red curves in panels (c) and (d).

$\hbar\omega_p = 0.13 \text{ eV}$ and $\hbar\gamma = 0.5 \text{ meV}$, and that of the time-modulated layer is $\epsilon_m(t) = \epsilon_s + \delta\epsilon \cos(\Omega t)$, with $\epsilon_s = 4$ the static permittivity, $\delta\epsilon$ the modulation strength, and Ω the modulation frequency. Here, the modulated layer is assumed to be lossless. Thus, all thermal radiation is sourced from the Drude metal. The Drude model used here can represent the permittivity of semiconductors of low doping density [46,47]. We assume that the top of the modulated layer is at $z = 0$, and the thickness of the time-modulated layer is $1 \mu\text{m}$. In the frequency domain, the thermally emitted electric fields $\mathbf{E}(\mathbf{r}, \omega)$ in the vacuum region ($z > 0$) can be obtained from the fluctuating currents $\mathbf{J}(\mathbf{r}, \omega)$ residing in the Drude metal as

$$\mathbf{E}(\mathbf{r}, \omega) = \frac{1}{2\pi} \int d\omega' \int d\mathbf{r}' G(\mathbf{r}, \mathbf{r}', \omega, \omega') \cdot \mathbf{J}(\mathbf{r}', \omega'), \quad (1)$$

where $G(\mathbf{r}, \mathbf{r}', \omega, \omega')$ is the Green's function of the time-modulated system. In a static system, we have $G(\mathbf{r}, \mathbf{r}', \omega, \omega') = G(\mathbf{r}, \mathbf{r}', \omega) 2\pi\delta(\omega - \omega')$. In contrast, for the time-modulated system with a single modulation frequency Ω as considered here, the Green's function is

given by $G(\mathbf{r}, \mathbf{r}', \omega, \omega') = \sum_n G(\mathbf{r}, \mathbf{r}', \omega, \omega') 2\pi\delta(\omega' - \omega_n)$ with $\omega_n = \omega + n\Omega$, and Eq. (1) becomes

$$\mathbf{E}(\mathbf{r}, \omega) = \sum_n \int d\mathbf{r}' G(\mathbf{r}, \mathbf{r}', \omega, \omega_n) \cdot \mathbf{J}(\mathbf{r}', \omega_n). \quad (2)$$

In this work, the focus is on the spatial coherence of thermally emitted fields. The physical quantity under investigation is the electric-field cross-spectral density tensor W_{ij} , given by [10,48]

$$W_{ij}(\mathbf{r}_1, \mathbf{r}_2, \omega, \omega') = \langle E_i(\mathbf{r}_1, \omega) E_j^*(\mathbf{r}_2, \omega') \rangle, \quad (3)$$

which characterizes the spatial correlation of the thermally emitted electric fields at two points \mathbf{r}_1 and \mathbf{r}_2 and at two frequencies ω and ω' , respectively. The superscript * in Eq. (3) denotes the complex conjugate operation. By using the fluctuation-dissipation theorem, from Eqs. (2) and (3), the cross-spectral density tensor of the electric fields in the upper half space can be calculated as

$$W_{ij}(\mathbf{r}_1, \mathbf{r}_2, \omega, \omega') = \sum_{n,m,v} H(\omega_n) \delta(\omega_n - \omega'_m) \times \int d\mathbf{r}' G_{iv}(\mathbf{r}_1, \mathbf{r}', \omega, \omega_n) G_{jv}^*(\mathbf{r}_2, \mathbf{r}', \omega', \omega'_m), \quad (4)$$

where $H(\omega_n) = 4\pi\epsilon_0\omega_n \text{Im}\{\epsilon(\omega_n)\} \Theta(\omega_n)$ with $\Theta(\omega) = \hbar\omega \{ \exp(\hbar\omega/k_B T) - 1 \}^{-1} + 1/2$. The integration over \mathbf{r}' is carried out inside the substrate (Drude metal here). We assume $T = 300 \text{ K}$ throughout this study. As seen in Eq. (2), an important aspect is that the thermal electromagnetic field at a frequency ω has contributions from sources at all frequencies ω_n . Consequently, as shown in Eq. (4), electric fields at two frequencies ω and ω' can correlate with each other if $\omega - \omega' = l\Omega$, with l being an integer. Such cross-frequency correlation for $l \neq 0$ arises from the photon frequency conversion as induced by the modulation with a frequency Ω . When Eq. (4) is applied to static systems, only the $n = m = 0$ term contributes and thus $W_{ij}(\mathbf{r}_1, \mathbf{r}_2, \omega, \omega') \propto \delta(\omega - \omega')$.

Because the system displayed in Fig. 1(a) is translationally invariant in the x - y plane, Eq. (4) can be written in \mathbf{k}_{\parallel} space as

$$W_{ij}(\mathbf{r}_1, \mathbf{r}_2, \omega, \omega') = \sum_{n,m,v} H(\omega_n) \int dz' \int \frac{d\mathbf{k}_{\parallel}}{(2\pi)^2} \times \bar{G}_{iv}(\mathbf{k}_{\parallel}, z_1, z', \omega, \omega_n) \times \bar{G}_{jv}^*(\mathbf{k}_{\parallel}, z_2, z', \omega', \omega'_m) \times e^{i\mathbf{k}_{\parallel} \cdot (\mathbf{R}_1 - \mathbf{R}_2)} \delta(\omega_n - \omega'_m), \quad (5)$$

where in-plane wave vectors $\mathbf{k}_{\parallel} = (k_x, k_y)$, in-plane coordinates $\mathbf{R} = (x, y)$, and \bar{G}_{iv} represents the Fourier

transform of G_{iv} in \mathbf{k}_{\parallel} space. We have developed a fluctuational electrodynamics formalism for time-modulated systems to calculate \bar{G}_{iv} and W_{ij} . More details about obtaining Eqs. (1), (2), and (4) as well as the formalism can be found in the Supplemental Material [49].

In Fig. 1(b), we present the dispersion of the surface plasmon mode, supported in the system. We consider two frequencies $\Omega_1 = 2\pi \times 13$ THz and $\Omega_2 = 2\pi \times 15$ THz separated by $\Omega = \Omega_2 - \Omega_1 = 2\pi \times 2$ THz. We use this value of Ω throughout this work unless otherwise specified. The structure supports a surface plasmon mode at Ω_1 but not at Ω_2 , as indicated in Fig. 1(b). Using Eq. (5), we obtain W_{zz} for $z_1 = z_2 = d$ in a plane at a subwavelength distance $d = 1 \mu\text{m}$ (approximately $1/20$ of the wavelength) above the modulated layer, as shown in Fig. 1(a).

We first explore W_{zz} for $\omega = \omega'$. In Fig. 1(c), normalized W_{zz} is plotted against the normalized in-plane separation distance $|R_1 - R_2|/\lambda$ for the frequencies Ω_1 and Ω_2 without time modulation (i.e., $\delta\epsilon = 0$). Because the surface plasmon dominates the electromagnetic response in the near-field regime, the correlation length is much larger at Ω_1 where the surface plasmon mode is present (blue curve) than at Ω_2 where no surface plasmon mode is available (red curve). The effect of such enhanced correlation length due to the presence of surface plasmons has been previously reported in Ref. [10]. In contrast, when the time modulation is present [Fig. 1(d)], we find the correlation length at Ω_2 (red curve) is drastically enhanced as compared with the unmodulated case shown in Fig. 1(c). Meanwhile, a slightly decreased correlation length at Ω_1 (blue curve) is observed [Fig. 1(d)]. The results here indicate that the coherence is transferred from Ω_1 to Ω_2 due to time modulation. Note that a modification of the correlation behavior in W_{zz} can also occur when the time-modulation induced transition occurs between two frequencies with surface plasmon modes available at both of them (see Fig. S1 in Supplemental Material [49]).

In order to illustrate better the underlining mechanism behind results shown in Fig. 1, based on Eq. (5), we define

$$\psi_{zz}^{(n)}(\mathbf{k}_{\parallel}, d, \omega, \omega_n) = \frac{4\epsilon_0^2 \omega_n^2}{\hbar \omega} \sum_v \int dz' \times |\bar{G}_{zv}(\mathbf{k}_{\parallel}, d, z', \omega, \omega_n)|^2. \quad (6)$$

W_{zz} is related to $\psi_{zz}^{(n)}$ as

$$\begin{aligned} W_{zz}(\mathbf{R}_1, \mathbf{R}_2, \omega, \omega') &= \frac{\hbar}{4\pi\epsilon_0} \sum_n \text{Im}\{\epsilon(\omega_n)\} \frac{\omega}{\omega_n} \Theta(\omega_n) \\ &\times \int d\mathbf{k}_{\parallel} \psi_{zz}^{(n)}(\mathbf{k}_{\parallel}, d, \omega, \omega_n) e^{i\mathbf{k}_{\parallel} \cdot (\mathbf{R}_1 - \mathbf{R}_2)} \delta(\omega - \omega') \end{aligned}$$

for $\omega = \omega'$. Here, $\psi_{zz}^{(n)}$ can be associated with a spectrally resolved transition coefficient (in the unit of $\text{m}^{-1} \text{eV}^{-1}$) from ω_n to ω for each \mathbf{k}_{\parallel} .

In Fig. 2(a), we plot $\psi_{zz}^{(n)}$ as a function of k_{\parallel} for $n = -1, 0$, and 1 at a fixed emitted field frequency $\omega = \Omega_1$ under the same type of time modulation as used in Fig. 1(d). The contributions to W_{zz} from higher order ($|n| > 1$) components are negligible. The dominant contribution is from the $n = 0$ component (i.e., $\psi_{zz}^{(0)}$). The spectrum of the $n = 0$ component for the modulated system [blue curve in Fig. 2(a)] is very similar to that of the unmodulated system [black dashed curve in Fig. 2(a)]. Both spectra peaks at $k_{\parallel} = 2.1\Omega_1/c$, which corresponds to the wave vector of the surface plasmon mode at Ω_1 , as shown in Fig. 1(b). Thus both spectra are dominated by the contribution from the surface plasmon mode. As a result, in real space, the correlation function W_{zz} oscillates at a period of approximately $2\pi/k_{\parallel} = \lambda/2.1$ for both the modulated and unmodulated cases, shown as the blue curve in Figs. 1(c) and 1(d), respectively. The $n = -1$ component represents

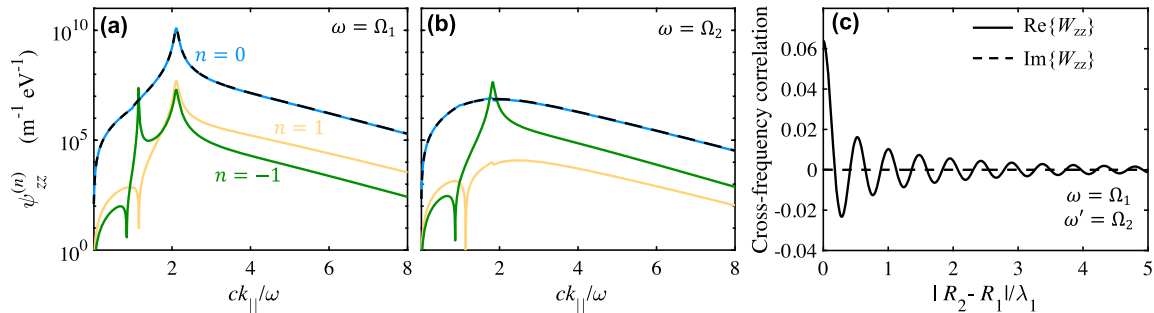


FIG. 2. (a),(b) Transition coefficient $\psi_{zz}^{(n)}$, defined in Eq. (6), as a function of k_{\parallel} at two fixed emitted field frequencies $\omega = \Omega_1$ (a) and $\omega = \Omega_2$ (b). Colored curves are for the system under the same time modulation as used in Fig. 1(d). Black dashed curves are for the unmodulated system as used in Fig. 1(c). (c) Real and imaginary parts of $W_{zz}(\omega = \Omega_1, \omega' = \Omega_2)$ as a function of normalized lateral separation distance under the same conditions as in Fig. 1(d). Note that here $\lambda_1 = 2\pi c/\Omega_1$, and W_{zz} is normalized to its value at Ω_1 and $|R_1 - R_2| = 0$ without time modulation.

a transition from $\Omega_1 - \Omega$ (thermal source frequency in the metal) to Ω_1 (emitted field frequency in vacuum). From Fig. 1(b), we observe that the system also supports a surface plasmon mode at $\Omega_1 - \Omega$ with $k_{\parallel} \approx 1.1\Omega_1/c$. Thus the spectrum of $n = -1$ component features two peaks around $k_{\parallel} = 1.1\Omega_1/c$ and $2.1\Omega_1/c$ due to contributions from surface plasmon modes at $\Omega_1 - \Omega$ and Ω_1 , respectively. Note that this transition between $\Omega_1 - \Omega$ to Ω_1 is not phase matched. The modulation is spatially uniform parallel to the surface, and yet the wave vectors of the surface plasmon modes at Ω_1 and $\Omega_1 - \Omega$ are different. Consequently, the strength of the transition is weak and thus the peak value of $\psi_{zz}^{(-1)}$ is much smaller than that of $\psi_{zz}^{(0)}$. The spectrum of $n = 1$ component features only one peak around $k_{\parallel} = 2.1\Omega_1/c$ instead of two peaks because no surface plasmon mode is available at $\Omega_1 + \Omega$ (i.e., Ω_2).

Significant differences in the behaviors of $\psi_{zz}^{(n)}$ can be found at $\omega = \Omega_2$. For the modulated system, the spectrum of its $n = 0$ component [blue curve in Fig. 2(b)] is very similar to that of the unmodulated system [black dashed line in Fig. 2(b)]. Also, both the $n = 0$ and $n = 1$ components do not exhibit any peaks since there is no surface plasmon mode at either Ω_2 or $\Omega_2 + \Omega$. On the other hand, the $n = -1$ components exhibit one peak around $k_{\parallel} = 2.1\Omega_1/c = 1.8\Omega_2/c$ because of the presence of the surface plasmon mode at $\Omega_2 - \Omega = \Omega_1$. Also, because of the presence of the surface plasmon modes, the $n = -1$ component dominates over the $n = 0$ and $n = 1$ components. Consequently, at $\omega = \Omega_2$, the modulated and the unmodulated systems exhibit completely different behavior in their coherence properties. In the unmodulated system, there is no long-range correlation behavior [Fig. 1(c), red curve] since there is no surface plasmon mode at Ω_2 . In the modulated system, there is a distinct long-range correlation behavior [Fig. 1(d), red curve]. As a result, the correlation function exhibits a corresponding oscillation period around $\lambda/1.8$ in real space [Fig. 1(d), red curve]. The results here indicate that time modulation can transfer coherence from one frequency to the others and hence can be used to drastically enhance the coherence of thermal radiation. Incidentally, there are dips appearing in the green and yellow curves of Figs. 2(a) and 2(b) when k_{\parallel} reaches the light line in vacuum [i.e., $k_{\parallel} \approx (\Omega_{1,2} \mp \Omega)/c$].

In Fig. 2(c) we plot the cross-frequency correlation $W_{zz}(\Omega_1, \Omega_2)$, which describes the correlation of the electric fields at two different frequencies Ω_1 and Ω_2 . The existence of such correlation for fields at two different frequencies $\Omega_1 \neq \Omega_2$ arises from the photonic transition as induced by dynamic modulation, and is a unique effect in time-modulated systems. Such cross-frequency correlation identically vanishes for passive systems. In Fig. 2(c), a rather long correlation length can be seen, as a consequence of the coherence enhancement as provided by the surface plasmon mode at Ω_1 . Note that W_{zz} is now a complex quantity

for $\omega \neq \omega'$, and in Fig. 2(c) both its real and imaginary parts are plotted.

In addition to control the coherence properties, the time modulation can also be used to manipulate the local density of optical states (LDOS). The LDOS is closely related to the energy density of the emitted thermal electromagnetic fields. Moreover, by controlling the LDOS, the decay rate of an emitter in the vicinity of structure can be manipulated [50–52]. As shown in Fig. 3(a), the system under investigation is the same as that used in Fig. 1(a). Here we consider the contribution to the LDOS for the z component of the electric field, at a location \mathbf{r}_0 which is at $z_0 = 5$ nm above the material-vacuum interface. Such a contribution is relevant for the spontaneous emission rate of a z -polarized dipole located at \mathbf{r}_0 . In time-modulated systems considered here, the LDOS can be calculated as

$$\frac{\text{LDOS}_z}{\text{LDOS}_0} = -3\text{Re} \left\{ \int \frac{k_{\parallel} dk_{\parallel}}{k_0^2} \epsilon_0 c \bar{G}_{zz}(k_{\parallel}, z_0, z_0, \omega, \omega) \right\}. \quad (7)$$

We have normalized the LDOS to its value in free space $\text{LDOS}_0 = \omega^2/3\pi^2 c^3$. Detailed derivation leading to Eq. (7) can be found in the Supplemental Material [49].

In Fig. 3(b), LDOS spectra for different modulation strengths are plotted. Without time modulation, the spectrum consists of a single peak around 13.6 THz (black dashed curve), as a result of the excitation of the surface plasmon resonance. In the presence of time modulation

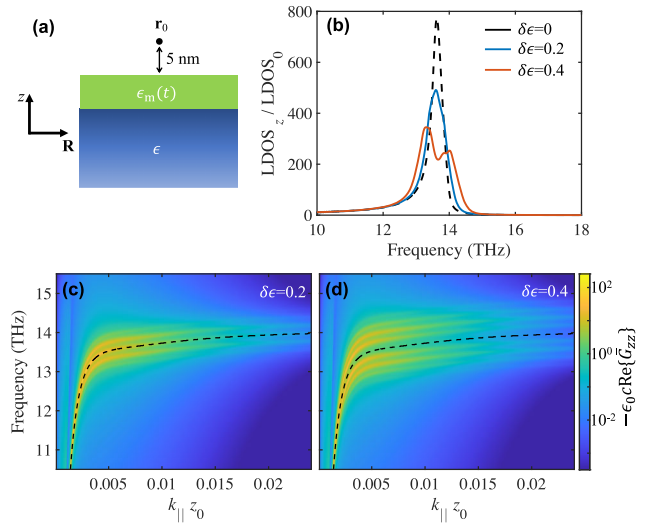


FIG. 3. (a) The photonic system used here is the same as that shown in Fig. 1(a) but with a modulation frequency of $\Omega = 2\pi \times 0.2$ THz. The z -polarized point dipole is placed at \mathbf{r}_0 in vacuum ($z_0 = 5$ nm away from the material surface). (b) LDOS spectra for different modulation strengths $\delta\epsilon$ (see legends inside). (c),(d) We plot $-\epsilon_0 c \text{Re}\{\bar{G}_{zz}(k_{\parallel}, z_0, z_0, \omega, \omega)\}$ from Eq. (7) as a function of frequency and in-plane wave number k_{\parallel} for $\delta\epsilon = 0.2$ (c) and $\delta\epsilon = 0.4$ (d). Black dashed curves represent the surface plasmon dispersion without time modulation.

with $\delta\epsilon = 0.2$, the spectrum consists of one broadened and damped peak (blue curve). With further increasing the modulation strength to $\delta\epsilon = 0.4$, the spectrum further broadens and splits, and its peak amplitude further decreases (red curve).

To analyze the LDOS spectra, we plot $-\epsilon_0 c \text{Re}\{\bar{G}_{zz}(k_{\parallel}, z_0, z_0, \omega, \omega)\}$, which appears in the integrand of Eq. (7), as a function of frequency and in-plane wave number k_{\parallel} in Figs. 3(c) and 3(d). In the absence of modulation, this quantity should peak at the dispersion relation of the surface plasmon, as indicated by the black dashed line in Figs. 3(c) and 3(d). In the presence of the modulation, this quantity peaks at the Floquet band structure of the system. For the case of $\delta\epsilon = 0.2$, in addition to the band at the dispersion relation of the surface plasmon, we see two prominent bands, with frequencies above and below the surface plasmon band respectively, due to the modulation. For the case of $\delta\epsilon = 0.4$, additional Floquet bands with frequencies above and below the surface plasmon band become visible. The broadening of the peaks in the LDOS is directly related to the Floquet band structure of the system.

We remark that such time-modulation induced coherence transfer can be also achieved with a lower (subterahertz) modulation frequency and a smaller modulation strength (with $\delta\epsilon/\epsilon_s$ around 0.01), as presented in the Supplemental Material [49]. The state-of-the-art electro-optical modulation with a response bandwidth approaching terahertz [53–55] can thus be exploited for this purpose. Moreover, in the present work we consider only direct photonic transition since our modulation is spatially uniform along the propagation direction of the surface plasmon. Additional opportunities may occur if one considers an indirect photonic transition [41] where the modulation is of the form $\delta\epsilon \cos(\Omega t - \beta x)$ with $\beta \neq 0$. Such a modulation may significantly enhance the coherence transition by coupling two surface plasmon modes at different frequencies together. When the material loss is included in the time-modulated layer, a generalization of the fluctuation-dissipation theorem is needed for time-modulated dispersive and lossy materials, which can also contribute to the thermal radiation as a source. However, by using our current formalism, we expect that the effects of coherence transfer should persist even when such modulated material with low losses is considered, since the physics is largely dominated by the properties of surface polaritons under modulations. Finally, the same concept and mechanism can be used to achieve the coherence transfer in systems based on surface phonon polaritons as well (see Supplemental Material [49] for more results).

In summary, we have shown that the spatial coherence of thermal radiation can be manipulated by temporally modulating the permittivity of the dielectric layer in a polaritonic structure. This is initiated by the time-modulation induced transition of energy and coherence from multiple thermal source frequencies to the emitted thermal radiation

frequency. As a result, correlations between two different radiation frequencies become possible in such system. Finally, we have also shown that the LDOS spectra can be controlled in the proximity of the time-modulated structure, due to the creation of the Floquet band structure in this system. Our findings open an exciting route toward coherence control of radiation from nanoscale thermal sources, dynamical thermal imaging, manipulating energy transfer among remotely located thermal or optical emitters, enhanced near-field radiative cooling, and modulating spontaneous emission rates of molecules.

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*shanhui@stanford.edu

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